

# SiC - photodiode JEC 0,3-4L



- characteristics :**
- ◆ spectral range 210 ... 380 nm
  - ◆ active area 0,22 mm<sup>2</sup>
  - ◆ high UV - response 0,13 A/W
  - ◆ TO 39-package
  - ◆ cap with lenscap
  - ◆ components are in conformity with RoHS and WEEE

- applications :**
- ◆ UV-measurement only
  - ◆ UV-source control (for instance in sterilizers)
  - ◆ flamedetection

## maximum ratings:

maximum reverse voltage	20	V
operating temperature range - 25 °C ... 70		°C
storage temperature range -40 °C ... 100		°C
soldering temperature (3s)	260	°C

## technical data :

test conditions, as not otherwise specified:  $\gamma_a = 25 \text{ °C}$ ,  $V_R = 0V$

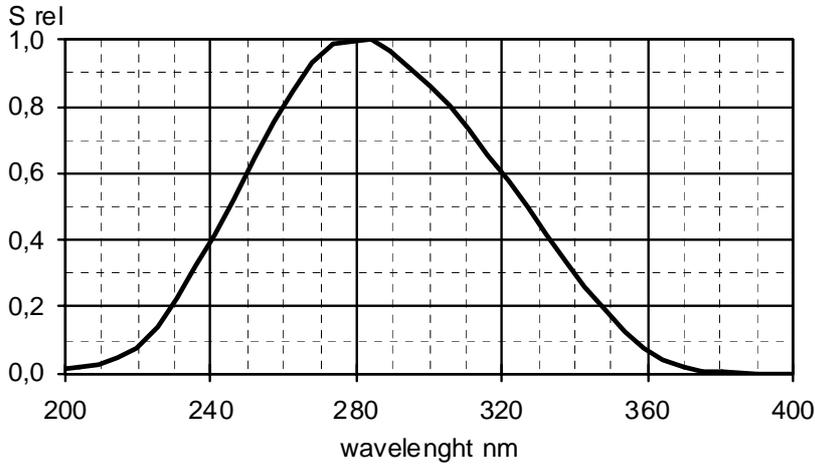
parameters	test conditions	min.	typ.	max.	unit
active area <sup>1)</sup>			11		mm <sup>2</sup>
spectral range		210		380	nm
maximum of spectral responsivity	$\lambda_{\max} = 275 \text{ nm}$		0,13		A/W
absolute spectral responsivity	$\lambda = 254 \text{ nm}$		0,11		A/W
short current (sunlight)	bright sun		200		nA
	cloudy		80		
dark current $I_R$	$V_R = 1 \text{ V}$		5		fA
capacitance			80		pF

<sup>1)</sup> effektive active area because of focusing of light by the lens

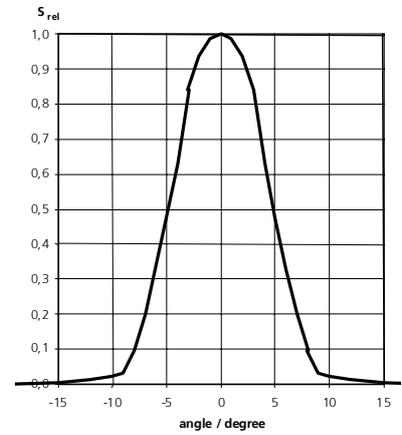
rev 3 (06/2009)

# JEC 0,3-4L

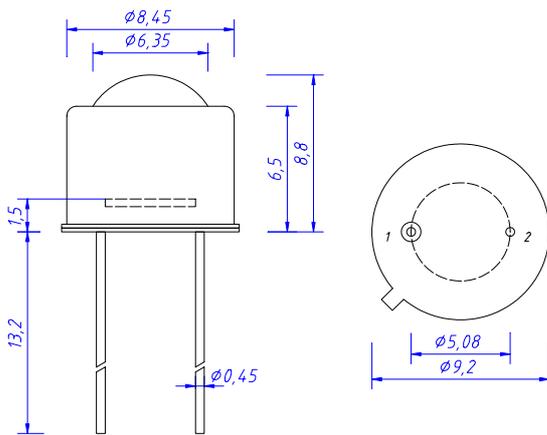
## relative spectral response



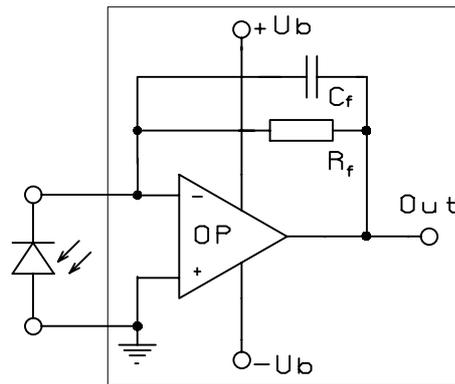
## response characteristic



## package dimensions



## application example



- 1 Kathode
- 2 Anode & Case

The application example shows a typical circuit.  $R_f$  is responsible for the gain of the circuit.  $C_f$  compensates the reverse junction capacitance of the photodiode and input capacitance of the OPV. The exact value of  $C_f$  depends on  $R_f$ , used OPV and capacitance of the circuit. A typical value is 1 pF.

The diagram shows dependence of amplitude of the application circuit with AD795,  $R_f = 50 \text{ M}\Omega$  and  $C_f = 0.5 \text{ pF}$ .

